# onsemi

MARKING

## Single 2-Input OR Gate

# MC74VHC1G32, MC74VHC1GT32

The MC74VHC1G32 / MC74VHC1GT32 is a single 2-input OR Gate in tiny footprint packages. The MC74VHC1G32 has CMOS-level input thresholds while the MC74VHC1GT32 has TTL-level thresholds.

The input structures provide protection when voltages up to 5.5 V are applied, regardless of the supply voltage. This allows the device to be used to interface 5 V circuits to 3 V circuits. Some output structures also provide protection when  $V_{CC} = 0$  V and when the output voltage exceeds  $V_{CC}$ . These input and output structures help prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

## Features

- $\bullet\,$  Designed for 2.0 V to 5.5 V V\_{CC} Operation
- 3.7 ns t<sub>PD</sub> at 5 V (typ)
- Inputs/Outputs Over-Voltage Tolerant up to 5.5 V
- IOFF Supports Partial Power Down Protection
- Source/Sink 8 mA at 3.0 V
- Available in SC-88A, SC-74A, TSOP-5, SOT-953 and UDFN6 Packages
- Chip Complexity < 100 FETs
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

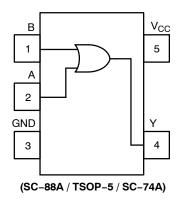


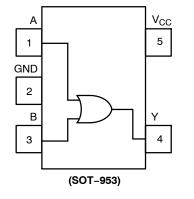
Figure 1. Logic Symbol

		MARKING DIAGRAMS
	SC-88A DF SUFFIX CASE 419A	□ □ □ ×× M• • •
	SC-74A DBV SUFFIX CASE 318BQ	
5 <b>1</b>	TSOP-5 DT SUFFIX CASE 483	5 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
		5 XXXAYW• • • 1
and a second	SOT-953 P5 SUFFIX CASE 527AE	
	UDFN6 1.45 x 1.0 CASE 517AQ	×M ●
1	UDFN6 1.2 x 1.0 CASE 517AA	× M ●
Ŷ	UDFN6 1.0 x 1.0 CASE 517BX	1 • X M
XX M	= Specific Devic = Date Code* = Pb-Free Pack	
(Note: Micro	odot may be in eith	er location)
*Date Code vary depend	orientation and/or ling upon manufact	position may uring location.

## **ORDERING INFORMATION**

See detailed ordering, marking and shipping information in the package dimensions section on page 7 of this data sheet.





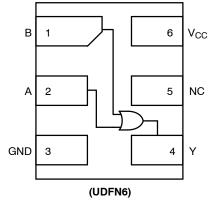


Figure 2. Pinout (Top View)

## **PIN ASSIGNMENT**

(SC-88A / TSOP-5 / SC-74A)

Pin	Function
1	В
2	A
3	GND
4	Y
5	V <sub>CC</sub>

## PIN ASSIGNMENT (SOT-953)

Function		
А		
GND		
В		
Y		
V <sub>CC</sub>		

### **PIN ASSIGNMENT (UDFN)**

Pin	Function
1	В
2	A
3	GND
4	Y
5	NC
6	V <sub>CC</sub>

## FUNCTION TABLE

Inp	out	Output
А	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

## MAXIMUM RATINGS

Symbol	с	Value	Unit	
V <sub>CC</sub>	DC Supply Voltage	TSOP-5, SC-88A (NLV) C-74A, SC-88A, UDFN6, SOT-553, SOT-953	-0.5 to +7.0 -0.5 to +6.5	V
V <sub>IN</sub>	DC Input Voltage S0	-0.5 to +7.0 -0.5 to +6.5	V	
V <sub>OUT</sub>	DC Output Voltage (NLV)	1Gxx	–0.5 to V <sub>CC</sub> + 0.5	V
		1GTxx Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +7.0 -0.5 to +7.0	
	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	$\begin{array}{c} -0.5 \text{ to } V_{CC} + 0.5 \\ -0.5 \text{ to } +6.5 \\ -0.5 \text{ to } +6.5 \end{array}$	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-20	mA
I <sub>OK</sub>	DC Output Diode Current (NLV)	1Gxx V <sub>OUT</sub> > V <sub>CC</sub> , V <sub>OUT</sub> < GND	±20	mA
		1GTxx V <sub>OUT</sub> < GND	-20	
	DC Output Diode Current	V <sub>OUT</sub> < GND	-20	mA
I <sub>OUT</sub>	DC Output Source/Sink Current		±25	mA
<sub>CC</sub> or I <sub>GND</sub>	DC Supply Current per Supply Pir	n or Ground Pin	±50	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Ca	se for 10 secs	260	°C
TJ	Junction Temperature Under Bias		+150	°C
$\theta_{JA}$	Thermal Resistance (Note 2)	SC-88A SC-74A SOT-553 SOT-953 UDFN6	377 320 324 254 154	°C/W
P <sub>D</sub>	Power Dissipation in Still Air	SC-88A SC-74A SOT-553 SOT-953 UDFN6	332 390 386 491 812	mW
MSL	Moisture Sensitivity		Level 1	-
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	_
V <sub>ESD</sub>	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 1000	V
I <sub>Latchup</sub>	Latchup Performance (Note 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Applicable to devices with outputs that may be tri-stated.

 Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
 HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.

4. Tested to EIA/JESD78 Class II.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol		Min	Max	Unit	
V <sub>CC</sub>	Positive DC Supply Voltage		2.0	5.5	V
V <sub>IN</sub>	DC Input Voltage		0	5.5	V
V <sub>OUT</sub>	DC Output Voltage (NLV)	1Gxx	0	V <sub>CC</sub>	V
		1GTxx Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	0 0 0	V <sub>CC</sub> 5.5 5.5	
	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	0 0 0	V <sub>CC</sub> 5.5 5.5	V
Τ <sub>Α</sub>	Operating Temperature Range		-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time	TSOP-5, SC-88A (NLV) V <sub>CC</sub> = 3.0 V to 3.6 V V <sub>CC</sub> = 4.5 V to 5.5 V	0 0	100 20	ns/V
	Input Rise and Fall Time	SC-74A, SC-88A, UDFN6, SOT-553, SOT-953 $V_{CC} = 2.0 V$ $V_{CC} = 2.3 V to 2.7 V$ $V_{CC} = 3.0 V to 3.6 V$ $V_{CC} = 4.5 V to 5.5 V$	0 0 0 0	20 20 10 5	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## DC ELECTRICAL CHARACTERISTICS (MC74VHC1G32)

		Test Vo		$V_{CC}$ $T_A = 25^{\circ}C$		С	-40°C ≤	T <sub>A</sub> ≤ 85°C	-55°C ≤ 1	A ≤ 125°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input		2.0	1.5			1.5		1.5		V
	Voltage		3.0	2.1			2.1		2.1		
			4.5	3.15			3.15		3.15		
			5.5	3.85			3.85		3.85		
VIL	Low-Level Input		2.0			0.5		0.5		0.5	V
	Voltage		3.0			0.9		0.9		0.9	
			4.5			1.35		1.35		1.35	
			5.5			1.65		1.65		1.65	
V <sub>OH</sub>	High-Level Output Voltage	$\begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OH} = -50 \ \mu\text{A} \\ I_{OH} = -50 \ \mu\text{A} \\ I_{OH} = -50 \ \mu\text{A} \\ I_{OH} = -4 \ m\text{A} \\ I_{OH} = -8 \ m\text{A} \end{array}$	2.0 3.0 4.5 3.0 4.5	1.9 2.9 4.4 2.58 3.94	2.0 3.0 4.5		1.9 2.9 4.4 2.48 3.80		1.9 2.9 4.4 2.34 3.66		V
V <sub>OL</sub>	Low-Level Output Voltage	$ \begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OL} = 50 \ \mu\text{A} \\ I_{OL} = 50 \ \mu\text{A} \\ I_{OL} = 50 \ \mu\text{A} \\ I_{OL} = 4 \ \text{mA} \\ I_{OL} = 8 \ \text{mA} \end{array} $	2.0 3.0 4.5 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.36 0.36		0.1 0.1 0.44 0.44		0.1 0.1 0.52 0.52	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5			±0.1		±1.0		±1.0	μA
I <sub>OFF</sub>	Power Off Leakage Current (NLV)	V <sub>IN</sub> = 5.5 V	0.0	-	-	1.0	_	10	_	10	μΑ
	Power Off Leakage Current	$V_{IN}$ = 5.5 V or $V_{OUT}$ = 5.5 V	0.0	-	-	1.0	-	10	-	10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5			1.0		20		40	μA

## DC ELECTRICAL CHARACTERISTICS (MC74VHC1GT32)

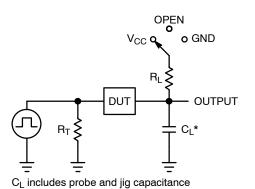
		Test	v <sub>cc</sub>	٦	Γ <sub>A</sub> = 25°	C	-40°C ≤ .	T <sub>A</sub> ≤ 85°C	-55°C ≤ 1	A ≤ 125°C		
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit	
V <sub>IH</sub>	High-Level Input		2.0	1.0			1.0		1.0		V	
	Voltage		3.0	1.4			1.4		1.4		1	
			4.5	2.0			2.0		2.0			
			5.5	2.0			2.0		2.0			
VIL	Low-Level Input		2.0			0.28		0.28		0.28	V	
	Voltage		3.0			0.45		0.45		0.45		
			4.5			0.8		0.8		0.8		
			5.5			0.8		0.8		0.8		
V <sub>OH</sub>	High-Level Output Voltage	$ \begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OH} = -50 \ \mu\text{A} \\ I_{OH} = -50 \ \mu\text{A} \\ I_{OH} = -50 \ \mu\text{A} \\ I_{OH} = -4 \ m\text{A} \\ I_{OH} = -8 \ m\text{A} \end{array} $	2.0 3.0 4.5 3.0 4.5	1.9 2.9 4.4 2.58 3.94	2.0 3.0 4.5		1.9 2.9 4.4 2.48 3.80		1.9 2.9 4.4 2.34 3.66		V	
V <sub>OL</sub>	Low-Level Output Voltage	$\begin{array}{l} V_{IN} = V_{IH} \mbox{ or } V_{IL} \\ I_{OL} = 50 \ \mu A \\ I_{OL} = 50 \ \mu A \\ I_{OL} = 50 \ \mu A \\ I_{OL} = 4 \ m A \\ I_{OL} = 8 \ m A \end{array}$	2.0 3.0 4.5 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.36 0.36		0.1 0.1 0.44 0.44		0.1 0.1 0.52 0.52	V	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5			±0.1		±1.0		±1.0	μΑ	
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0			1.0		10		10	μΑ	
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5			1.0		20		40	μΑ	
I <sub>CCT</sub>	Increase in Quiescent Supply Current per Input Pin	One Input: V <sub>IN</sub> = 3.4 V; Other Input at V <sub>CC</sub> or GND	5.5			1.35		1.5		1.65	mA	

## AC ELECTRICAL CHARACTERISTICS

				T	A = 25°	С	-40°C ≤ 1	Γ <sub>A</sub> ≤ 85°C	–55°C ≤ T	A ≤ 125°C	
Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Мах	Min	Мах	Unit
t <sub>PLH</sub> ,	Propagation Delay,	C <sub>L</sub> = 15 pF	3.0 to 3.6		4.8	7.9		9.5		11.5	ns
t <sub>PHL</sub>	A to Y (Figures 3 and 4)	C <sub>L</sub> = 50 pF			6.1	11.4		13.0		15.5	
		C <sub>L</sub> = 15 pF	4.5 to 5.5		3.7	5.5		6.5		8.0	
		C <sub>L</sub> = 50 pF			4.4	7.5		8.5		10.0	
C <sub>IN</sub>	Input Capacitance				4.0	10		10		10	pF
C <sub>OUT</sub>	Output Capacitance	Output in High Impedance State			6.0						pF
											r

		Typical @ 25°C, $V_{CC}$ = 5.0 V		l
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)	8.0	pF	

5.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no-load dynamic power consumption;  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .

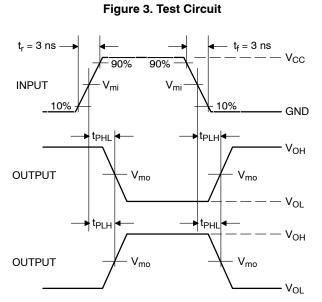


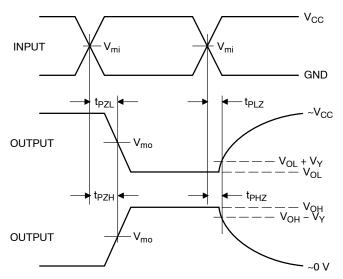
 $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )

f = 1 MHz

Test	Switch Position	С <sub>L</sub> , pF	$R_{L}, \Omega$
t <sub>PLH</sub> / t <sub>PHL</sub>	Open	See AC Characteristics Table	Х
t <sub>PLZ</sub> / t <sub>PZL</sub>	V <sub>CC</sub>		1 k
t <sub>PHZ</sub> / t <sub>PZH</sub>	GND		1 k

X = Don't Care





## Figure 4. Switching Waveforms

		V <sub>mo</sub> , V		
V <sub>CC</sub> , V	V <sub>mi</sub> , V	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub> , t <sub>PZH</sub> , t <sub>PHZ</sub>	V <sub>Y</sub> , V
3.0 to 3.6	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3
4.5 to 5.5	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3

### **ORDERING INFORMATION**

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
MC74VHC1G32DFT1G	SC-88A	V4	Q2	3000 / Tape & Reel
MC74VHC1G32DFT1G-L22038**	SC-88A	V4	Q2	3000 / Tape & Reel
MC74VHC1G32DFT2G	SC-88A	V4	Q4	3000 / Tape & Reel
MC74VHC1G32DFT2G-L22038**	SC-88A	V4	Q4	3000 / Tape & Reel
NLVVHC1G32DFT1G*	SC-88A	V4	Q2	3000 / Tape & Reel
NLVVHC1G32DFT2G*	SC-88A	V4	Q4	3000 / Tape & Reel
M74VHC1GT32DFT1G	SC-88A	VN	Q2	3000 / Tape & Reel
M74VHC1GT32DFT2G	SC-88A	VN	Q4	3000 / Tape & Reel
NLVVHC1GT32DFT2G*	SC-88A	VN	Q4	3000 / Tape & Reel
NLVVHC1GT32DFT1G*	SC-88A	VN	Q2	3000 / Tape & Reel
MC74VHC1G32DBVT1G	SC-74A	V4	Q4	3000 / Tape & Reel
MC74VHC1GT32DBVT1G	SC-74A	VN	Q4	3000 / Tape & Reel
MC74VHC1G32DTT1G**	TSOP-5	V4	Q4	3000 / Tape & Reel
NLVVHC1G32DTT1G*	TSOP-5	V4	Q4	3000 / Tape & Reel
NLV74VHC1GT32DTT1G*	TSOP-5	VN	Q4	3000 / Tape & Reel
M74VHC1GT32DTT1G**	TSOP-5	VN	Q4	3000 / Tape & Reel
MC74VHC1G32P5T5G	SOT-953	F	Q2	8000 / Tape & Reel
MC74VHC1G32P5T5G-L22088**	SOT-953	F	Q2	8000 / Tape & Reel
MC74VHC1GT32P5T5G	SOT-953	Q	Q2	8000 / Tape & Reel
MC74VHC1GT32P5T5G-L22088**	SOT-953	Q	Q2	8000 / Tape & Reel
MC74VHC1G32MU1TCG	UDFN6, 1.45 x 1.0, 0.5P	3 (Rotated 90° CW)	Q4	3000 / Tape & Reel
MC74VHC1GT32MU1TCG (In Development)	UDFN6, 1.45 x 1.0, 0.5P	T (Rotated 180° CW)	Q4	3000 / Tape & Reel
MC74VHC1G32MU2TCG	UDFN6, 1.2 x 1.0, 0.4P	3	Q4	3000 / Tape & Reel
MC74VHC1GT32MU2TCG (In Development)	UDFN6, 1.2 x 1.0, 0.4P	5	Q4	3000 / Tape & Reel
MC74VHC1G32MU3TCG	UDFN6, 1.0 x 1.0, 0.35P	F (Rotated 180° CW)	Q4	3000 / Tape & Reel
MC74VHC1GT32MU3TCG (In Development)	UDFN6, 1.0 x 1.0, 0.35P	Q	Q4	3000 / Tape & Reel

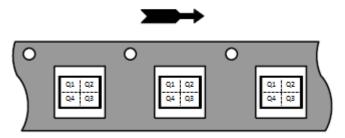
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

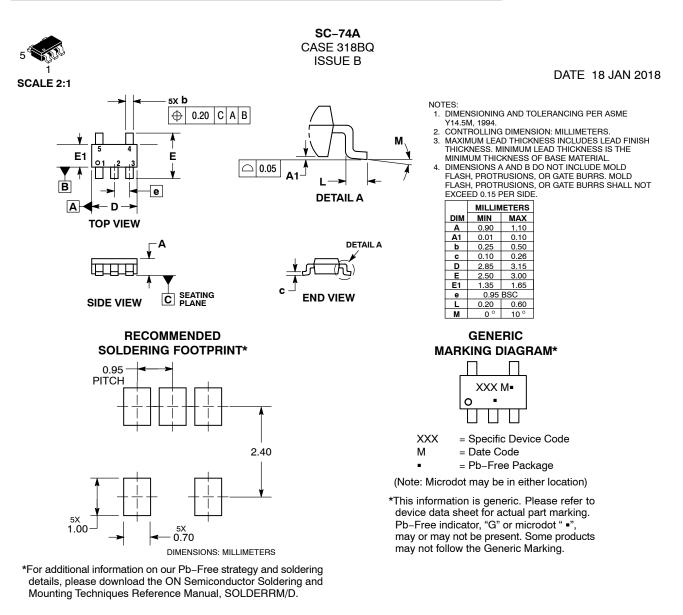
\*\* Please refer to NLV specifications for this device.

## Pin 1 Orientation in Tape and Reel

## Direction of Feed







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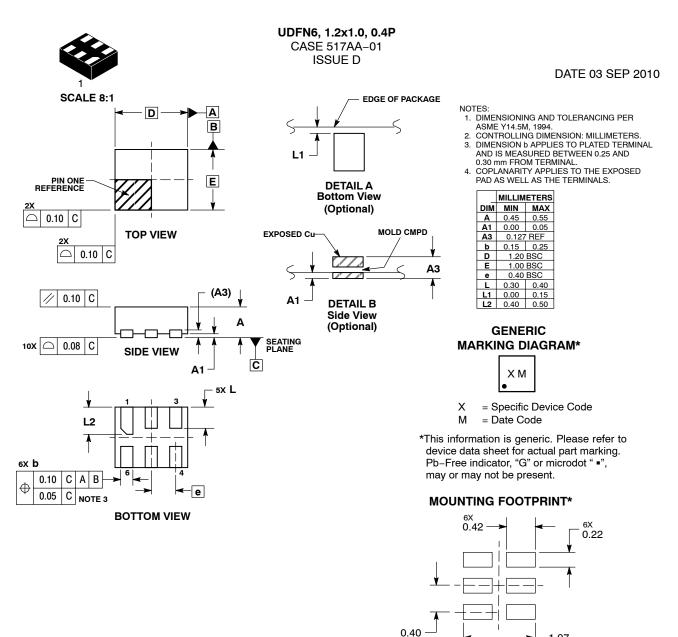
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DIMENSIONS: MILLIMETERS

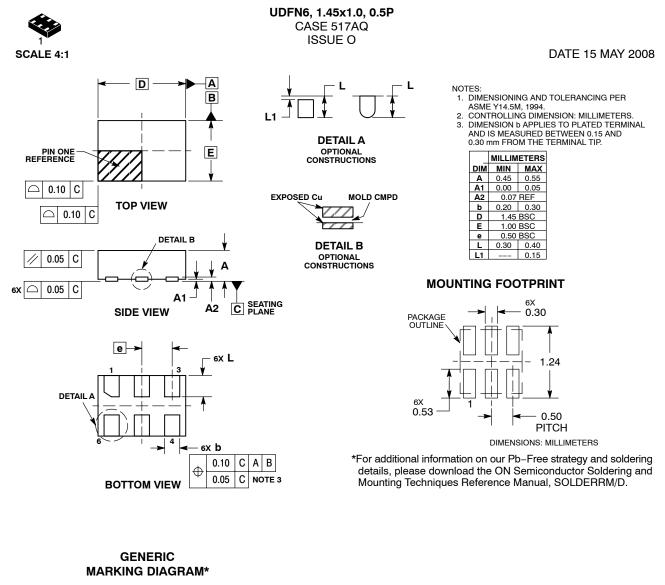
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\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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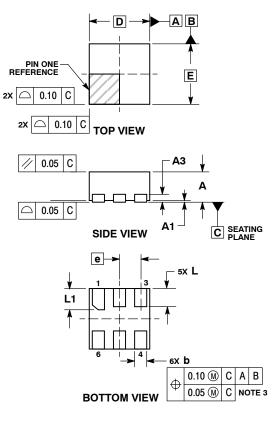
- X = Specific Device Code
- M = Date Code
- \*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

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SCALE 4:1



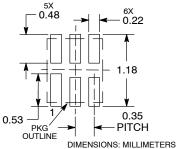
UDFN6, 1x1, 0.35P CASE 517BX **ISSUE O** 

#### DATE 18 MAY 2011

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN A DE ADD & OR MULTICAL TERMINAL TR
- AND 0.20 MM FROM TERMINAL TIP.
  PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

BURH	BURRS AND MOLD FL				
	MILLIMETERS				
DIM	MIN	MIN MAX			
Α	0.45	0.55			
A1	0.00	0.00 0.05			
A3	0.13	0.13 REF			
b	0.12 0.22				
D	1.00 BSC				
E	1.00 BSC				
е	0.35 BSC				
L	0.25 0.35				
L1	0.30	0.40			

#### RECOMMENDED **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## GENERIC **MARKING DIAGRAM\***



X = Specific Device Code M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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SCALE 4:1

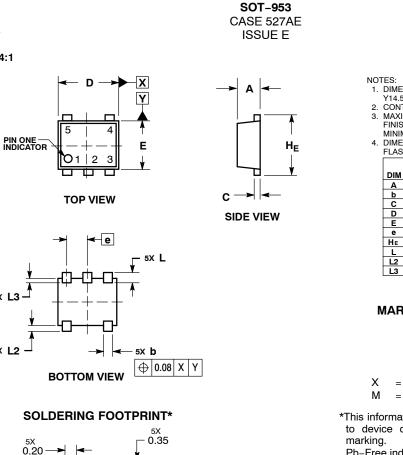
5X L3

5X L2

PACKAGE OUTLINE

0.35 PITCH





#### DATE 02 AUG 2011

NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL. 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.34	0.37	0.40	
b	0.10	0.15	0.20	
С	0.07	0.12	0.17	
D	0.95	1.00	1.05	
E	0.75	0.80	0.85	
е		0.35 BSC		
HE	0.95	1.00	1.05	
L	(	0.175 RE	F	
L2	0.05	0.10	0.15	
L3			0.15	

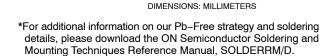
## GENERIC **MARKING DIAGRAM\***

= Specific Device Code

= Month Code

\*This information is generic. Please refer to device data sheet for actual part

Pb-Free indicator, "G" or microdot " .", may or may not be present.



L

1.20

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